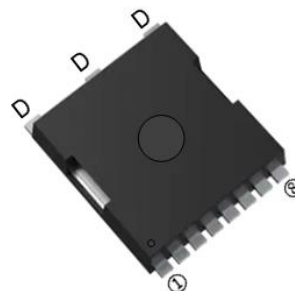


RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

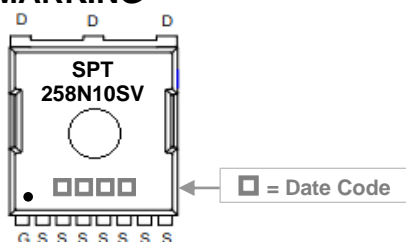
FEATURES

- Shielded Gate Trench Technology
- High Speed Power Smooth Switching
- Enhanced Body diode dv/dt capability
- 100% UIS Tested, 100% R_g Tested
- Super Low Gate Charge
- Green Device Available

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MARKING

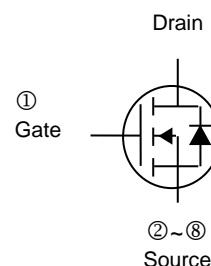


PACKAGE INFORMATION

Package	MPQ	Leader Size
TOLL-8	2K	13 inch

ORDER INFORMATION

Part Number	Type
SPT258N10SV-C	Lead (Pb)-free and Halogen-free



ABSOLUTE MAXIMUM RATINGS ($T_J=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ⁴ (Silicon Limited)	I_D	$T_C=25^{\circ}C$	258
		$T_C=100^{\circ}C$	183
Continuous Drain Current ¹ (Package Limited)	I_D	$T_C=25^{\circ}C$	240
		$T_A=25^{\circ}C$	27
Pulsed Drain Current ²	I_{DM}	800	A
Power Dissipation	P_D	$T_C=25^{\circ}C$	341
		$T_A=25^{\circ}C$	2.5
Operating Junction & Storage Temperature Range	T_J, T_{STG}	-55~175	$^{\circ}C$
Thermal Resistance Ratings			
Thermal Resistance Junction-Ambient ¹	$R_{\theta JA}$	60	$^{\circ}C/W$
Thermal Resistance Junction-Case ¹	$R_{\theta JC}$	0.44	

ELECTRICAL CHARACTERISTICS ($T_J=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	100	-	-	V	$V_{GS}=0V, I_D=250\mu A$	
Gate-Threshold Voltage	$V_{GS(th)}$	2	-	4	V	$V_{DS}=V_{GS}, I_D=250\mu A$	
Forward Transfer Conductance ²	g_{fs}	-	75	-	S	$V_{DS}=5V, I_D=20A$	
Gate-Source Leakage Current	I_{GSS}	-	-	± 100	nA	$V_{GS}=\pm 20V, V_{DS}=0V$	
Drain-Source Leakage Current	$T_J=25^\circ C$	I_{DSS}	-	-	10	uA	$V_{DS}=100V, V_{GS}=0V$
	$T_J=100^\circ C$		-	-	100		
Static Drain-Source On-Resistance ³	$R_{DS(ON)}$	-	1.97	2.5	m Ω	$V_{GS}=10V, I_D=20A$	
Gate Resistance	R_g	-	1.5	-	Ω	$f=1MHz$	
Total Gate Charge	Q_g	-	106	-	nC	$I_D=20A$ $V_{DD}=50V$ $V_{GS}=10V$	
Gate-Source Charge	Q_{gs}	-	24	-			
Gate-Drain Change	Q_{gd}	-	22	-			
Turn-on Delay Time	$T_{d(on)}$	-	28	-	nS	$V_{DD}=50V$ $I_D=20A$ $V_{GS}=10V$ $R_G=10\Omega$	
Rise Time	T_r	-	22	-			
Turn-off Delay Time	$T_{d(off)}$	-	52	-			
Fall Time	T_f	-	13	-			
Input Capacitance	C_{iss}	-	7684	-	pF	$V_{GS}=0V$ $V_{DS}=50V$ $f=1MHz$	
Output Capacitance	C_{oss}	-	1140	-			
Reverse Transfer Capacitance	C_{rss}	-	21	-			
Source-Drain Diode							
Diode Forward Voltage ³	V_{SD}	-	0.9	1.2	V	$I_F=20A, V_{GS}=0V$	
Reverse Recovery Time	t_{rr}	-	75	-	nS	$I_F=20A, V_R=50V,$ $dlf/dt=100A/\mu s$	
Reverse Recovery Charge	Q_{rr}	-	120	-	nC		

Notes:

1. The data tested by surface mounted on a 1 inch² FR-4 board with 2oz copper.
2. Pulse Width $\leq 10\mu s$, Duty Cycle $\leq 2\%$.
3. The Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. The Pulse width limited by maximum junction temperature.

CHARACTERISTIC CURVES

Fig 1. Typical Output Characteristics

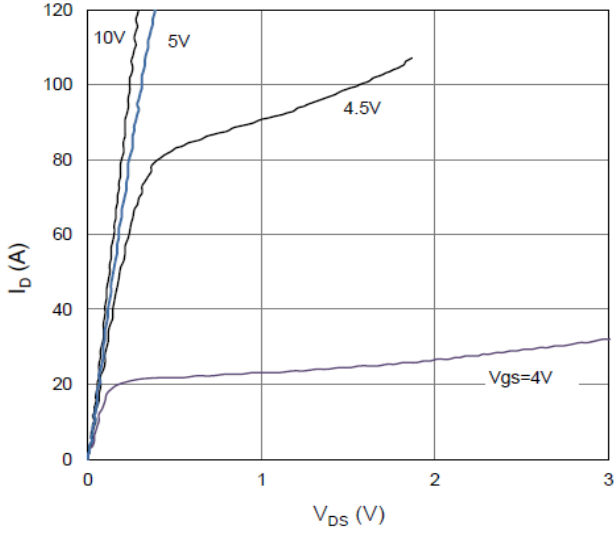


Figure 2. On-Resistance vs. Gate-Source Voltage

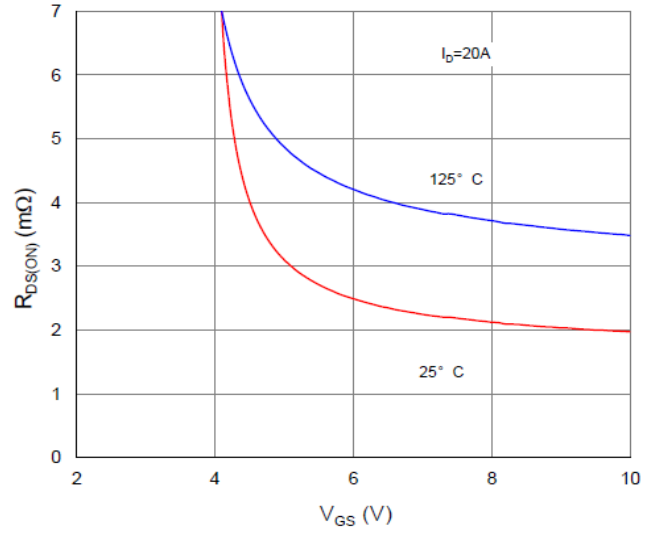


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

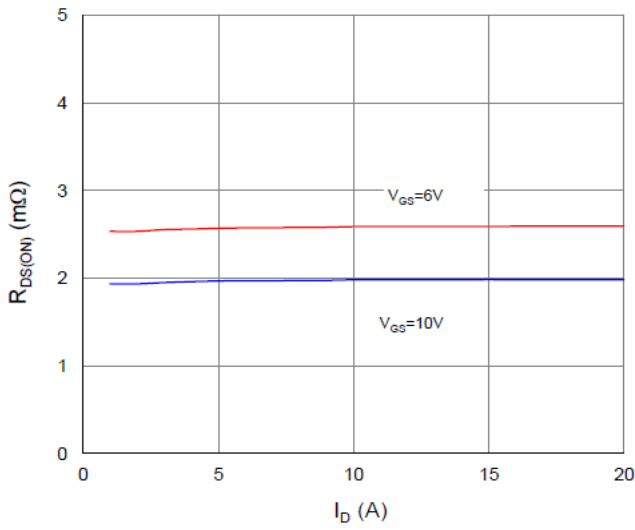


Figure 4. Normalized On-Resistance vs. Junction Temperature

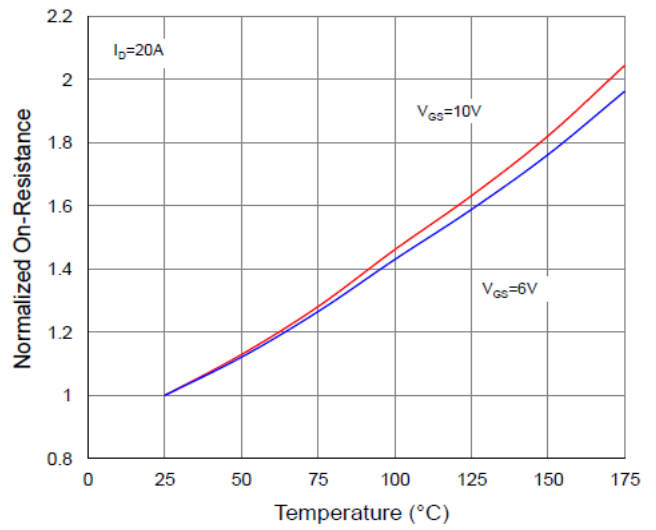


Figure 5. Typical Transfer Characteristics

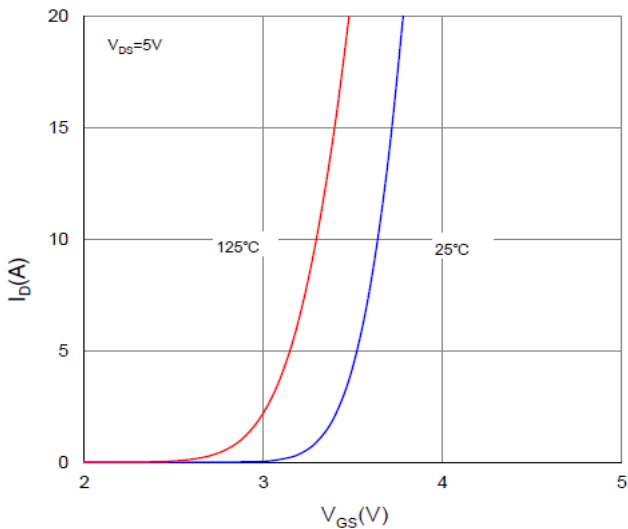
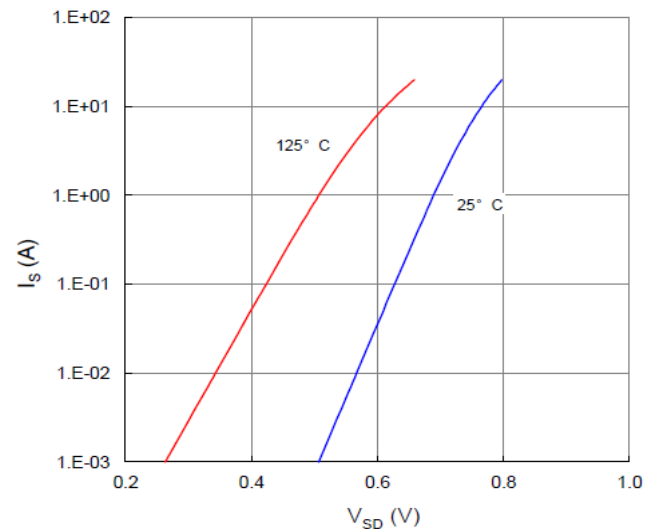


Figure 6. Typical Source-Drain Diode Forward Voltage



CHARACTERISTIC CURVES

Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage

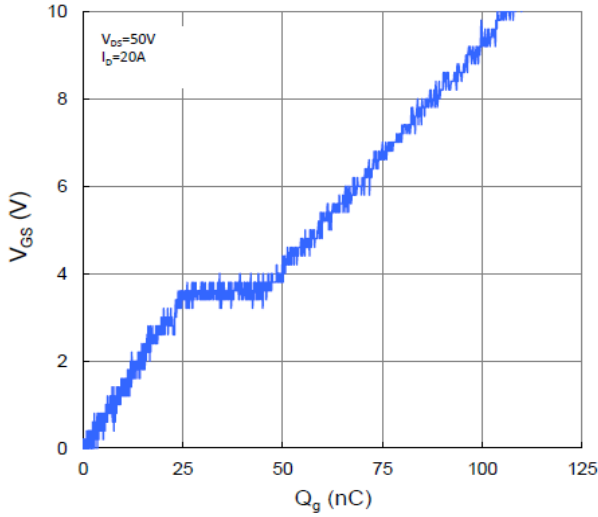


Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

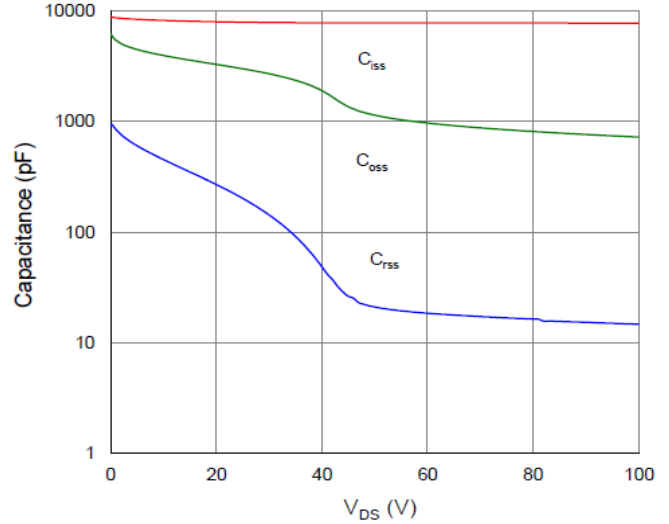


Figure 9. Maximum Safe Operating Area

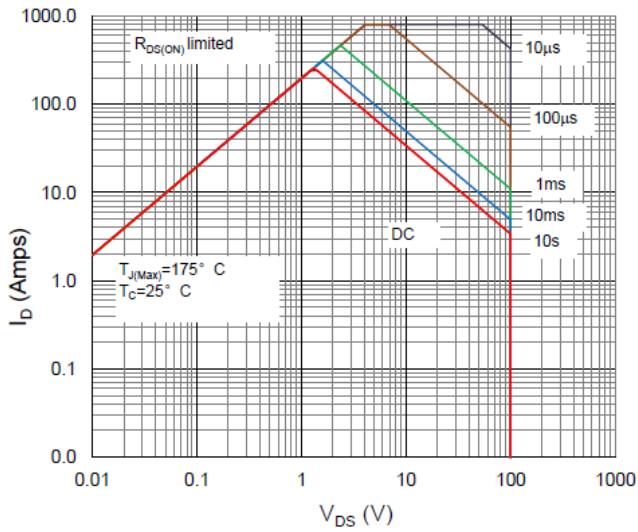


Figure 10. Maximum Drain Current vs. Case Temperature

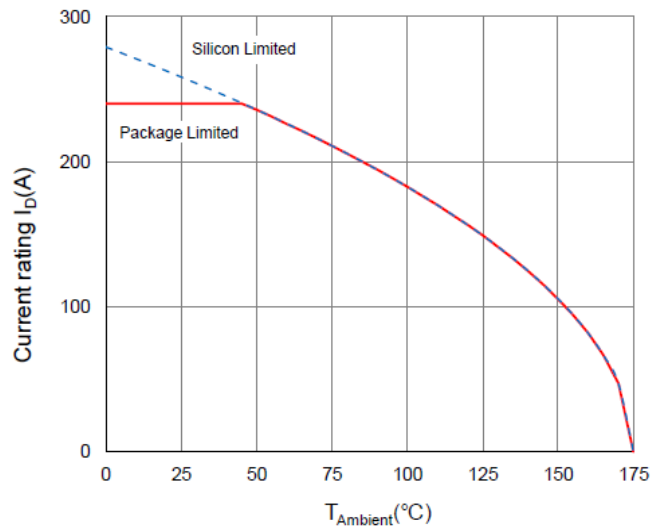
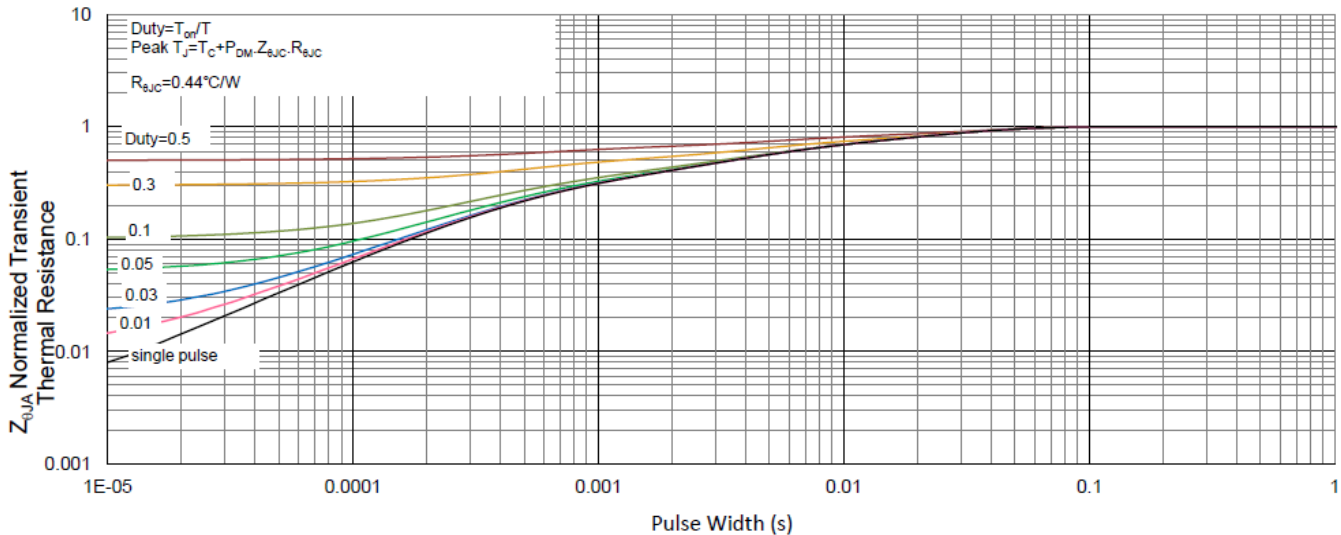
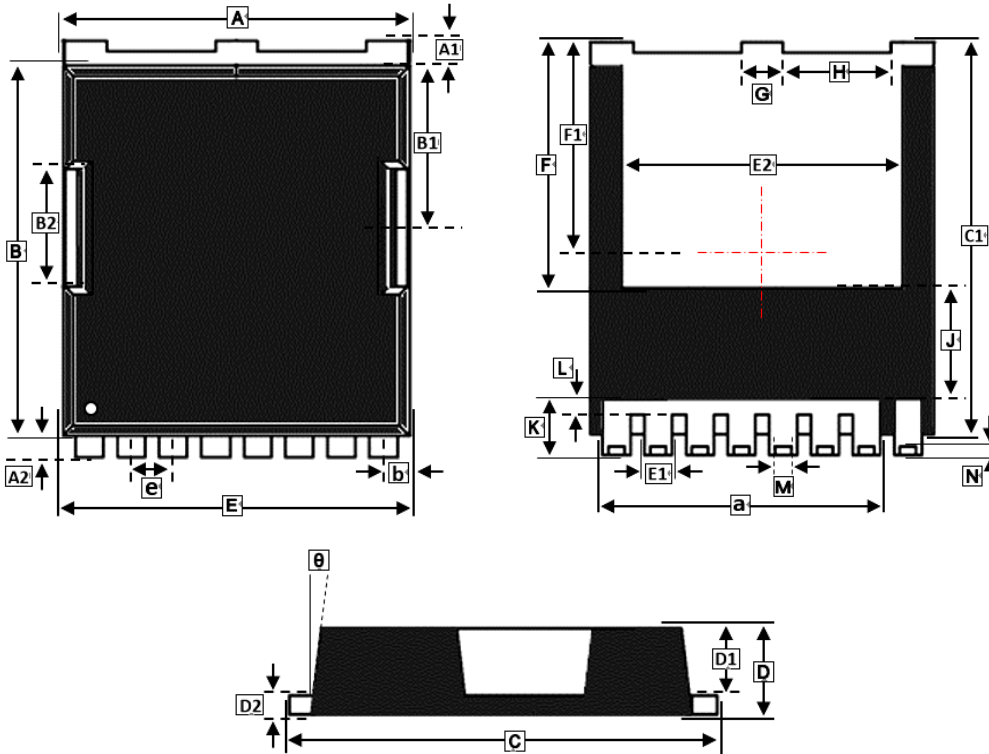


Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Ambient



PACKAGE OUTLINE DIMENSIONS

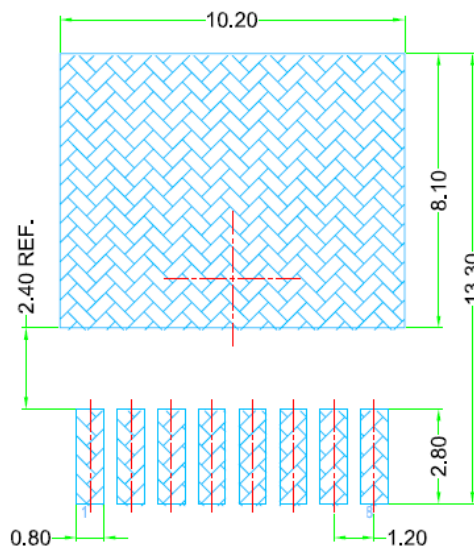
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REF.	Millimeter	
	Min.	Max.
A	9.70	9.90
A1	0.60	0.80
A2	0.50	0.70
B	10.28	10.48
B1	4.45	4.65
B2	3.20	3.40
C	11.58	11.78
C1	10.98	11.18
D	2.20	2.40
D1	1.70	1.90
D2	0.40	0.60
E	9.80	10.00
E1	0.70	0.90
E2	8.00	8.20
F	6.95 BSC.	
F1	5.89 BSC.	
G	1.10	1.30
H	3.00	3.20
J	2.80 REF.	
K	1.40	2.10
L	0.30	0.80
M	0.46 REF.	
N	0.10 REF.	
theta	10° REF.	
a	8.00 REF.	
b	0.60	0.80
e	1.20 BSC.	

MOUNTING PAD LAYOUT

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*Dimensions in millimeters